

SKiiP 792 GB 170 - 370 WT/FT

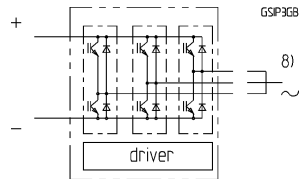
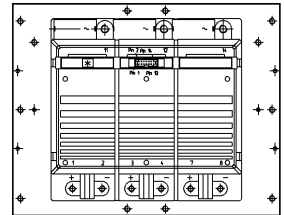
Absolute Maximum Ratings		Values	Units
Symbol	Conditions ¹⁾		
IGBT & Inverse Diode			
V _{CES}		1700	V
V _{CC} ⁹⁾	Operating DC link voltage	1200	V
I _C	T _{heatsink} = 25 °C	750	A
I _{CM}	T _{heatsink} = 25 °C; t _p < 1 ms	1500	A
T _J ³⁾	IGBT & Diode	-55 ... +150	°C
V _{isol} ⁴⁾	AC, 1 min.	4000	V
I _F	T _{heatsink} = 25 °C	620	A
I _{FM}	T _{heatsink} = 25 °C; t _p < 1 ms	1500	A
I _{FSM}	t _p = 10 ms; sin.; T _J = 150 °C	6480	A
I ² t (Diode)	t _p = 10 ms; T _J = 150 °C	210	kA ² s
Driver			
V _{S1}	Stabilized power supply	18	V
V _{S2} ¹⁰⁾	Nonstabilized power supply	30	V
dv/dt	Primary to second. side	75	kV/μs
T _{op} , T _{stg}	Operating / stor. temperature (version FT)	-25(0) ... +85(70)	°C

Characteristics		min.	typ.	max.	Units
Symbol	Conditions ¹⁾				
V _{(BR)CES}	Driver without power supply	≥ V _{CES}	-	-	V
I _{CES}	V _{GE} = 0 { T _J = 25 °C	-	1,2	-	mA
	V _{CE} = V _{CES} { T _J = 125 °C	-	45	-	mA
V _{CESat} ¹¹⁾	I _C = 562 A { T _J = 25 (125) °C }	-	3,3 (4,6)	-	V
V _{CESat} ¹¹⁾	I _C = 750 A { T _J = 25 (125) °C }	-	3,75 (5,65)	-	V
I _{CETrip}	T _J = 125 °C; V _s = 15 V ± 0,6V	≥ 940	-	-	A
C _{CHC}	per SKiiPPACK AC side	-	2,4	-	nF
L _{CE}	Top (Bottom)	-	5	-	nH
t _{d(on)}	V _{CC} = 1200 V I _C = 750 A T _J = 125 °C inductive load	-	200	-	ns
t _{d(on)Driver}		-	1,2	-	μs
t _r		-	300	-	ns
t _{d(off)}		-	2	-	μs
t _{d(off)Driver}		-	1,2	-	μs
t _f		-	120	-	ns
E _{on} + E _{off}		-	975	-	mJ
Inverse Diode ²⁾					
V _F ¹¹⁾ = V _{EC}	I _F = 675 A { T _J = 25 (125) °C }	-	2,3 (2,1)	-	V
	I _F = 900 A { T _J = 25 (125) °C }	-	2,6 (2,5)	-	V
V _{TO}	T _J = 125 °C	-	0,9	-	V
r _T	T _J = 125 °C	-	1,8	-	mΩ
E _{on} + E _{off}	I _F = 750 A; T _J = 125 °C	-	90	-	mJ
Thermal Characteristics					
R _{thjh}	per IGBT	-	0,027	-	K/W
R _{thjh}	per diode	-	0,09	-	K/W
T _{tp}	Over temperature protection	109	115	121	°C
R _{thha} ⁶⁾	P16/280 F; V _{air} = 285 m ³ / h	-	0,036	-	K/W
Mechanical Data					
M _{dc}	for DC terminals, SI Units	4	-	6	Nm
M _{ac}	for AC terminals, SI Units	8	-	10	Nm
Case			S3		

SKiiPPACK® SK integrated intelligent Power PACK halfbridge

**SKiiP 792 GB 170
+ Driver 370 WT/FT ⁷⁾**
Preliminary Data

Case S3



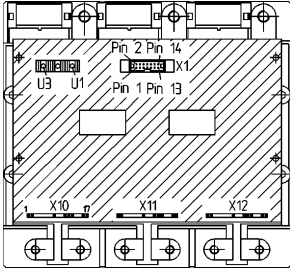
Features

- Low thermal impedance
- Optimal thermal management with integrated heatsink
- Pressure contact technology with increased power cycling capability, compact design
- Low stray inductance
- High power, small losses
- Overtemp. protection
- Short circuit protection
- Isolated power supply

- 1) T_{heatsink} = 25 °C, unless otherwise specified
- 2) CAL = Controlled Axial Lifetime Technology (soft and fast)
- 3) without driver
- 4) Driver input to DC link/AC output or DC link/AC output to heatsink
- 6) other heatsink on request
- 7) W - Driver wire input
F - Fiber optic input
T - Temperature protection
- 8) AC connection busbars must be connected by user, copper busbars available on request
- 9) with SK-DC link (low inductance)
- 10) 24 V supply voltage selective
- 11) Chip voltage drop
- 12) thermal reference for R_{thjh}; R_{thha}

SKiiPACK®
SK integrated
intelligent Power PACK
halfbridge

SKiiP 792 GB 170
+ Driver 370 WT/FT 3)
Preliminary Data



SKiiP 792 GB 170 - 370 WT/FT
Driver for Halfbridge

Absolute Maximum Ratings				
Symbol	Conditions	Values	Units	remark
V_{S1}	supply voltage primary	18	V	pin 8 / 9
$V_{S2}^{1)}$	supply voltage primary	30	V	pin 6 / 7
I_{outmax}	output peak current max.	± 10	A	
I_{outAV}	output average current	± 100	mA	
f_{swmax}	switching frequency max.	11	kHz	
V_{CE}	collector emitter voltage			
	sense across IGBT	1700	V	
dv/dt	rate of rise and fall of voltage (secondary to primary side)	75	kV/ μ s	
$V_{isol IO}$	Isol. test volt. IN/OUT (RMS; 1 min)	4	kV~	
$V_{isol 12}$	Isol. test volt. output 1 - output 2	1,7	kV=	
T_{op}, T_{stg}	operating / stor. temperature	-25...+85	°C	WT-version
T_{op}, T_{stg}	operating / stor. temperature	0...+70	°C	FT-version

Characteristics				
Symbol	Conditions	Values	Units	remark
V_{S1}	supply voltage	15,0 \pm 4%	V	pin 8 / 9
$V_{S2}^{1)}$	supply voltage	24,0	V	pin 6 / 7
		+20%/-15%		
V_{uvs}	supply voltage monitoring	13 / 19,5	V	15 V / 24 V
I_{S01}	sup. current pr.side (standby)	200	mA	15 V supply
$I_{S02}^{1)}$	sup. current pr.side (standby)	160	mA	24 V supply
I_{S1}	sup. current pr.side (max)	680	mA	15 V supply
$I_{S2}^{1)}$	sup. current pr.side (max)	530	mA	24 V supply
V_{IT+}	input thresh. volt. (high) min	12,9	V	
V_{IT-}	input thresh. volt. (low) max.	2,1	V	
$V_{GE(on)}$	turn-on output gate voltage	15	V	
$V_{GE(off)}$	turn-off output gate voltage	-8	V	
$t_{d(on)}$	propagation delay time on	1,2	μ s	typ.
$t_{d(off)}$	propagation delay time off	1,2	μ s	typ.
t_{TD}	dead time of interlock	3	μ s	typ.
V_{CEstat}	V_{CE} -thresh. st. monitoring	6,5	V	typ.
$V_{ol}^{2)}$	logic low output voltage	< 500	mV	15 mA
$V_{oH}^{2)}$	logic high output voltage	max. 30	V	
$t_{pdon-error}$	propag. delay time-on error	6	μ s	typ.
$t_{p RESET}$	min. pulse width error memory RESET	5	μ s	
T_{err}	max. temperature	115 \pm 6	°C	
I_{AOmax}	max. output current	± 5	mA	pin 12

Features

- CMOS compatible inputs
- Short circuit protection by V_{CE} monitoring and soft switch off
- Drive interlock top/bottom
- Isolation by transformers
- Supply undervoltage protection
- Overtemperature protection
- Fiber-optic connection (option)

- 1) 24 V - supply voltage selective
2) Open collector output, external pull-up resistor necessary
3) W - Driver wire input
F - Fiber optic input
T - Temperature protection